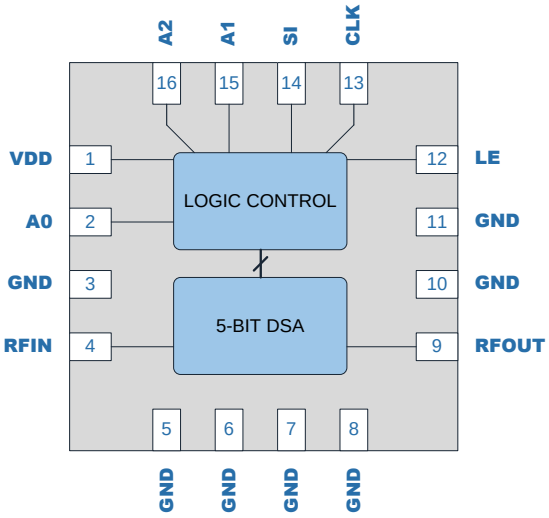
RFSA3523

5MHz to 6000MHz, Digital Step Attenuator

The RFMD's RFSA3523 is a 5-bit digital step attenuator (DSA) that features high linearity over the entire 15.5dB gain control range with 0.5dB steps. The RFSA3523 uses serial control interface. The RFSA3523 has a low insertion loss of 1.4dB at 2GHz. Patent pending circuit architecture provides overshoot-free transient switching performance. External address pins allow up to eight DSAs to be controlled on a single bus. The RFSA3523 is available in a 3mm x 3mm QFN package.



Functional Block Diagram

Package: QFN, 16-Pin,
3.0mm x 3.0mm x 0.85mm

Features

- 5-Bit, 15.5dB Range, 0.5dB Step
- Patent Pending Circuit Architecture
- Overshoot-free Transient Switching Performance
- Frequency Range 5MHz to 6000MHz
- High Linearity, IIP3 >55dBm
- Serial Control Interface
- Fast Switching Speed, <120nsec Typical
- Serial Addressable Supports Up to Eight Addresses
- Single Supply 3V to 5V Operation
- RF Pins Have No DC Voltage, Can be DC Grounded Externally
- Power-up Default Setting Is Maximum Attenuation

Applications

- 2G through 4G Base Stations
- Point-to-Point
- WiMax/WiFi
- Test Equipment

Ordering Information

RFSA3523SQ	Sample bag with 25 pieces
RFSA3523SR	7" Reel with 100 pieces
RFSA3523TR7	7" Reel with 2500 pieces
RFSA3523PCK-410	5MHz to 6000MHz PCBA with 5-piece sample bag

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421
For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com.

DS150128

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage (V_{DD})	-0.5 to +6.0	V
All Other DC and Logic Pins (Supply Voltage Must Be Applied Prior to Any Other Pin Voltages)	-0.5 to V_{DD}	V
Maximum Input Power at RFIN Pin at 85°C Case Temperature	+30	dBm
Maximum Input Power at RFOUT Pin at 85°C Case Temperature	+27	dBm
Storage Temperature Range	-40 to +150	°C
ESD Rating - Human Body Model (HBM)	1000	V
Moisture Sensitivity Level	MSL1	

Caution! ESD sensitive device.

RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Recommended Operating Condition

Parameter	Specification			Unit
	Min	Typ	Max	
Operating Temperature Range (RF Input power handling de-rates above 85°C)	-40		+105	°C
Operating Junction Temperature			125	°C
Supply Voltage	2.7		5.5	V

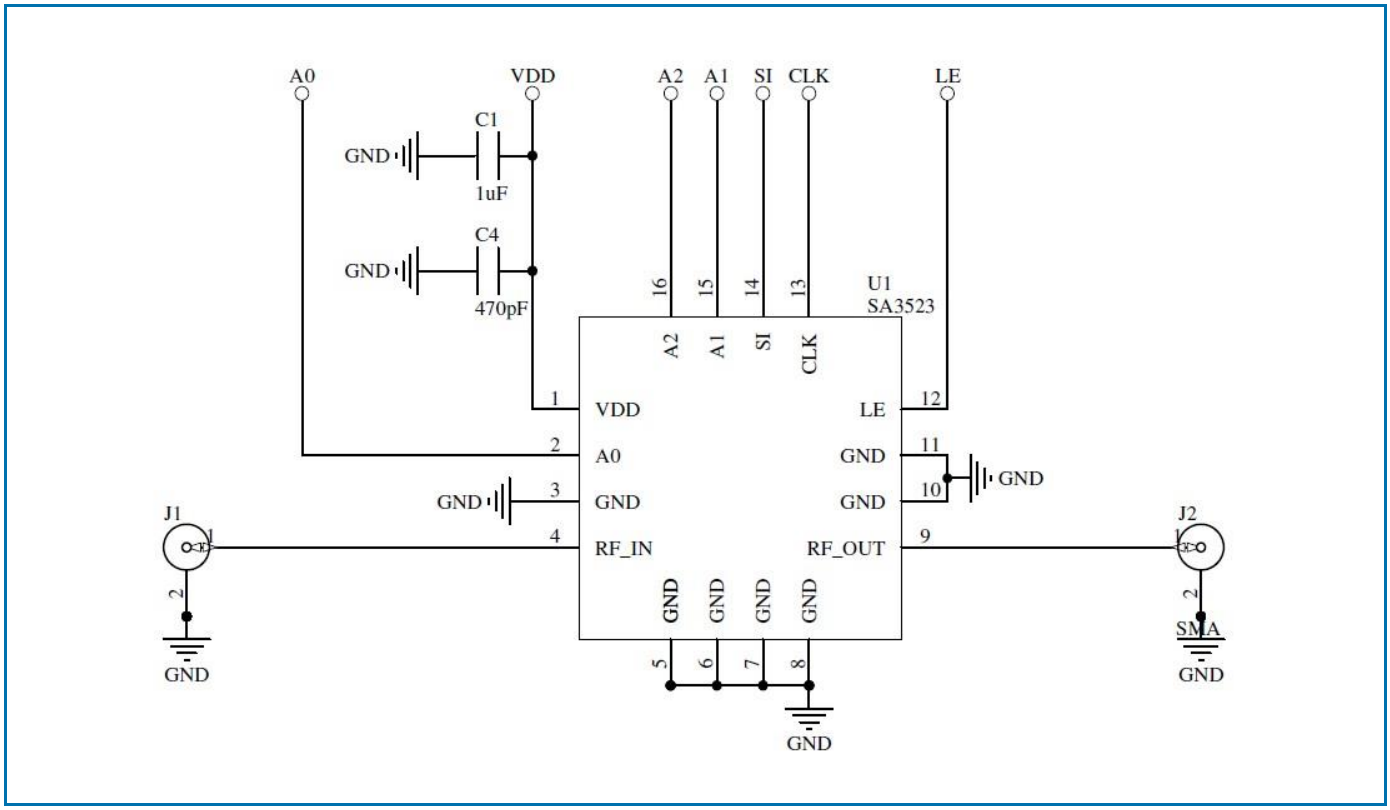
Nominal Operating Parameters

Parameter	Specification			Unit	Condition
	Min	Typ	Max		
General Performance					
Supply Current		180		µA	Steady state operation, current draw during attenuation state transitions is higher.
Thermal Resistance		55		°C/W	At maximum attenuation state with RF power applied to the RFIN pin.
RF Input Power at RFIN Pin			27	dBm	Continuous operation at +85°C case temperature
RF Input Power at RFOUT Pin			20	dBm	
RF Performance					
Frequency Range	5		6000	MHz	
Insertion Loss		1.4		dB	2000MHz, 0dB attenuation
Attenuation Range		15.5		dB	0.5dB step size
Absolute Attenuation Error	±(0.2 + 4%)			dB	
Input IP3		55		dBm	
Input P0.1dB		30		dBm	
Return Loss		15		dB	
Input and Output Impedance		50		Ω	

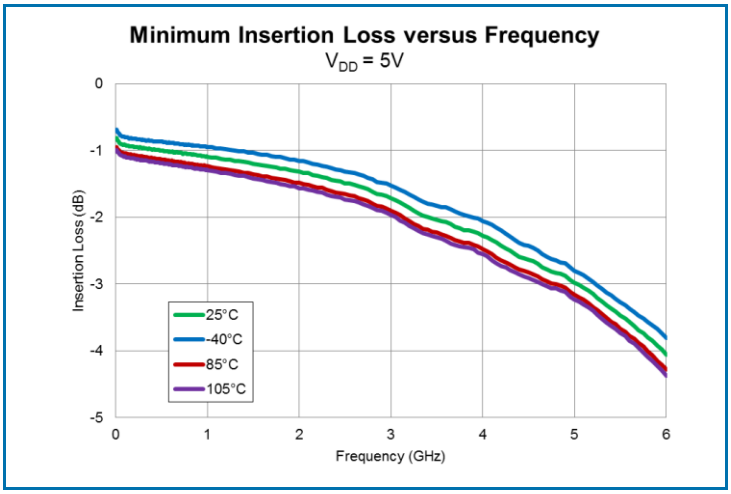
Parameter	Specification			Unit	Condition
	Min	Typ	Max		
RF Performance – Continued					
Switching Speed		120		nsec	50% control to 10%/90% RF
Successive Step Phase Delta		2		Deg	2000MHz
Control					
Digital Logic Low			0.63	V	
Digital Logic High	1.17			V	

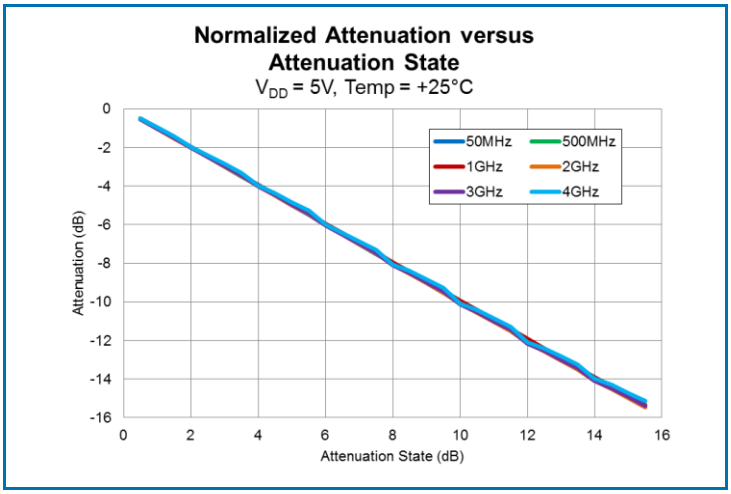
Note: Typical performance at these conditions: Temp = +25°C, 2000MHz, 5V Supply Voltage

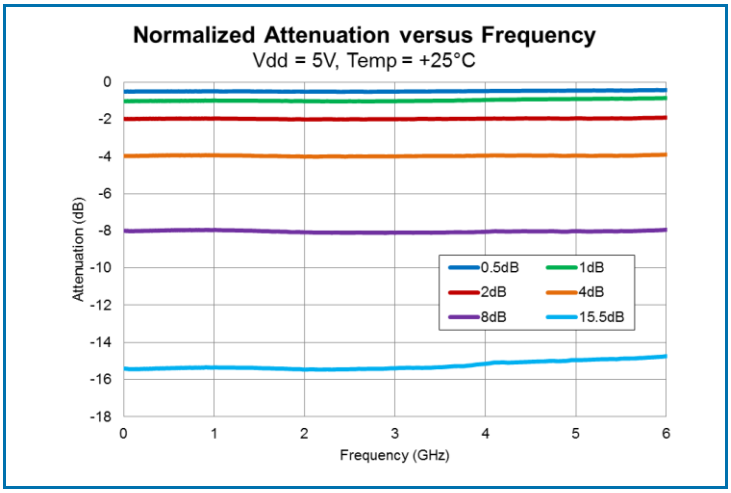
Typical Application Schematic

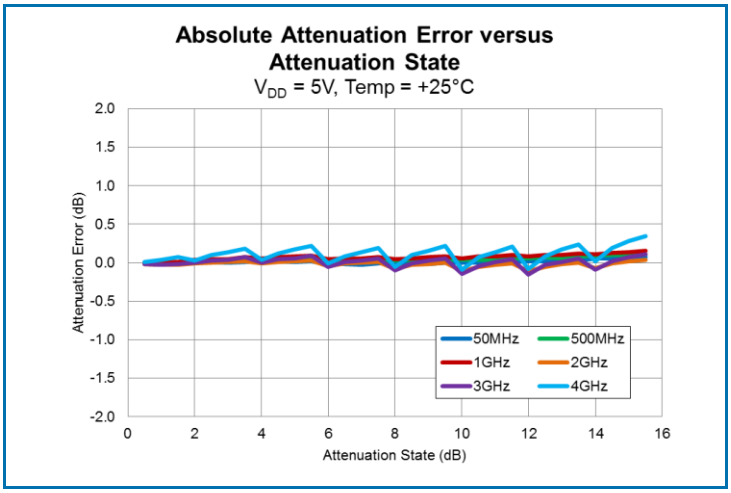


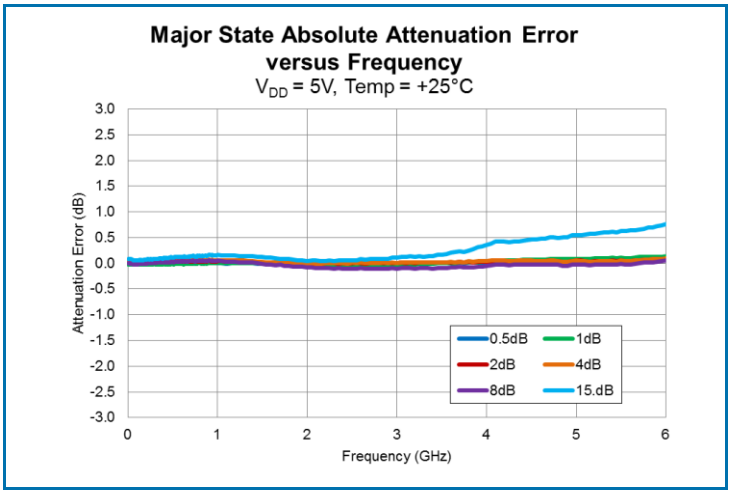
Typical Performance:

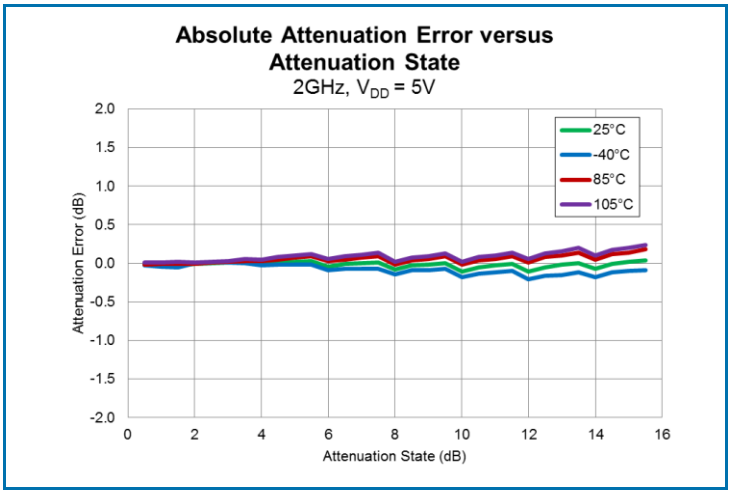












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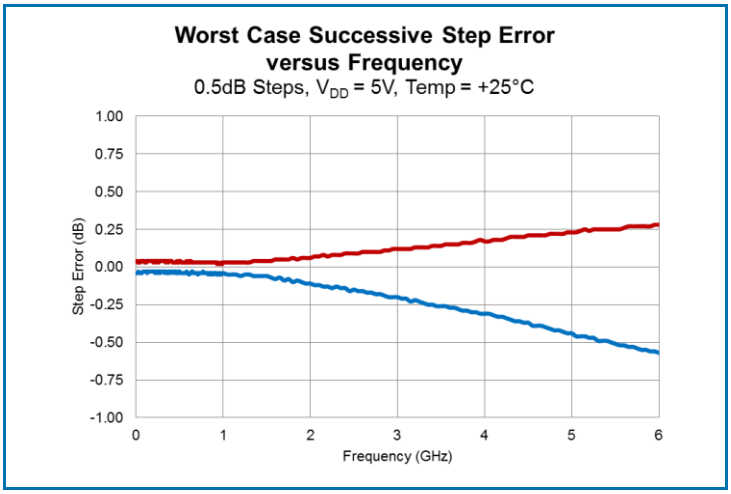
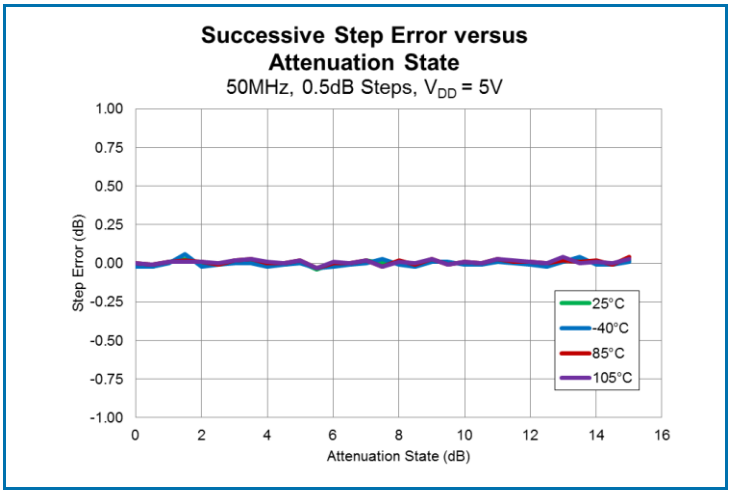
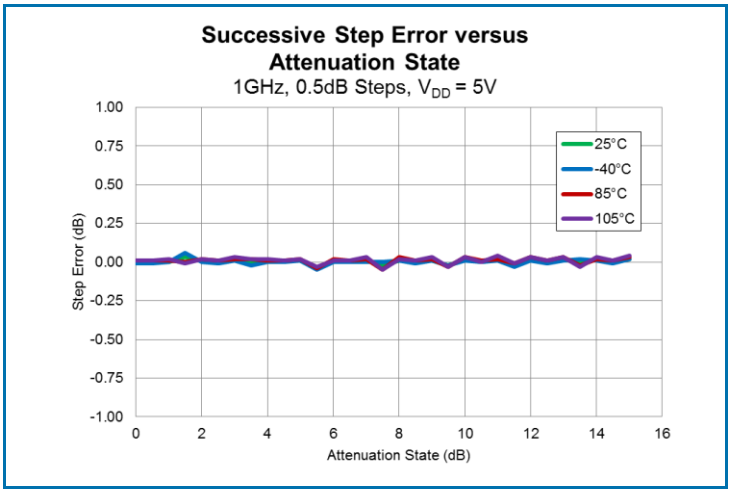
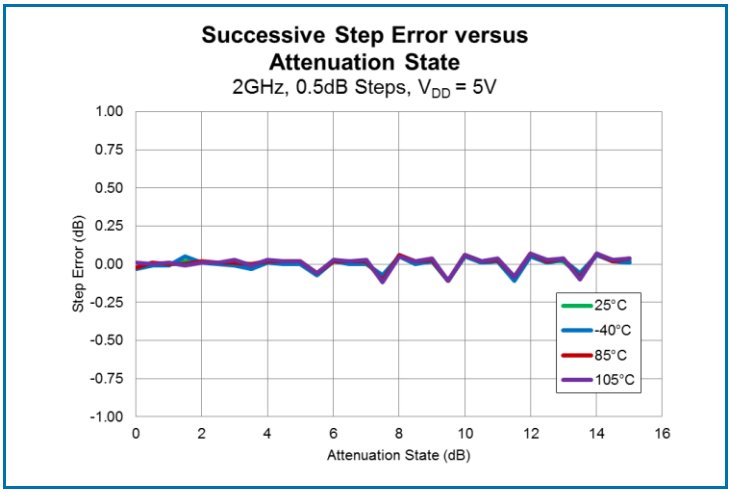
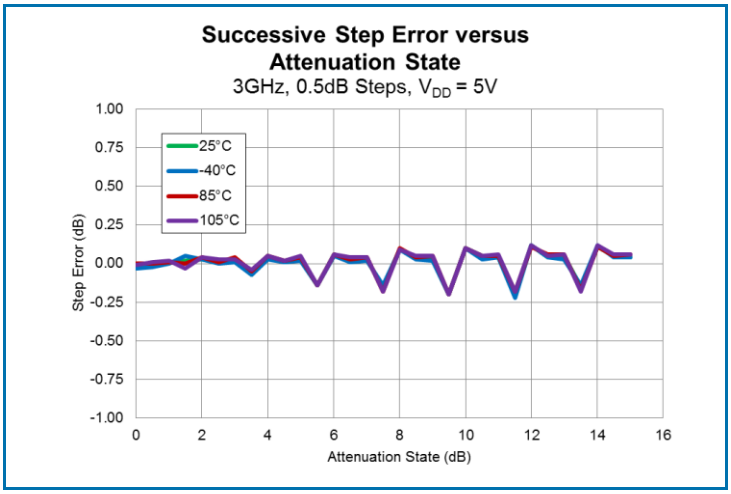
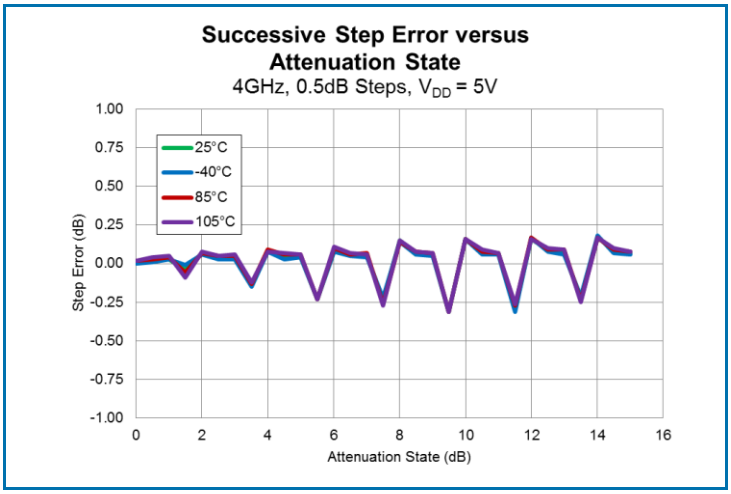






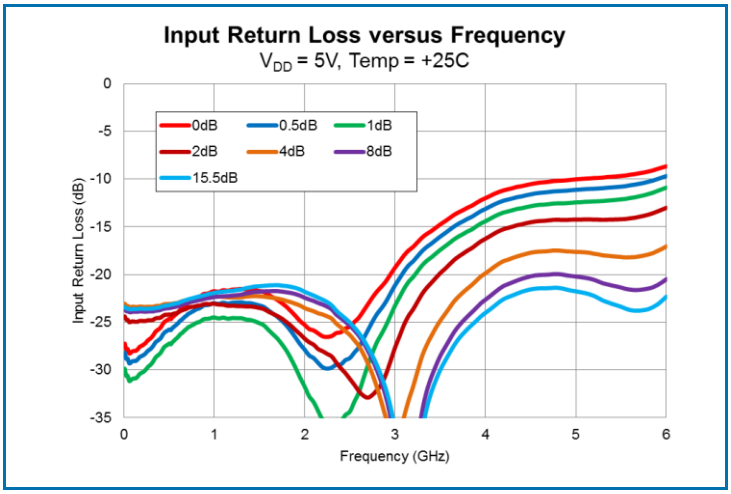


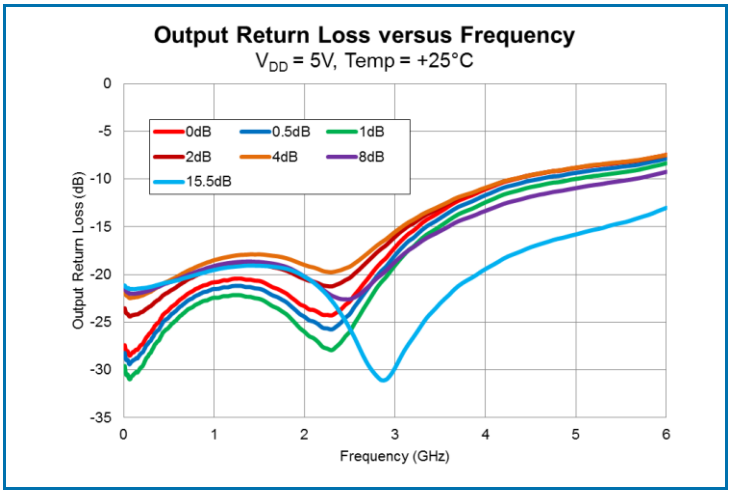


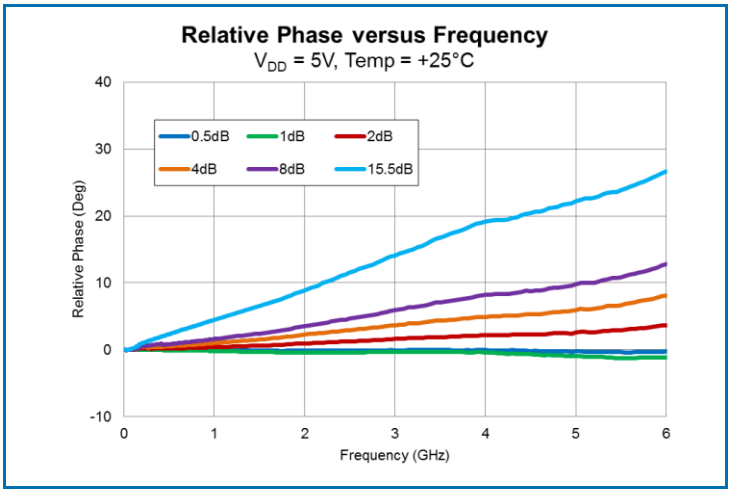


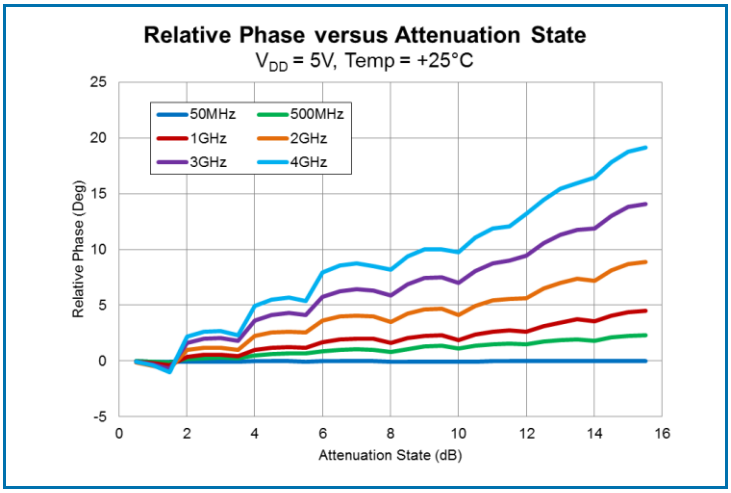
Note: Attenuator remains monotonic if step error is less than +0.5dB.

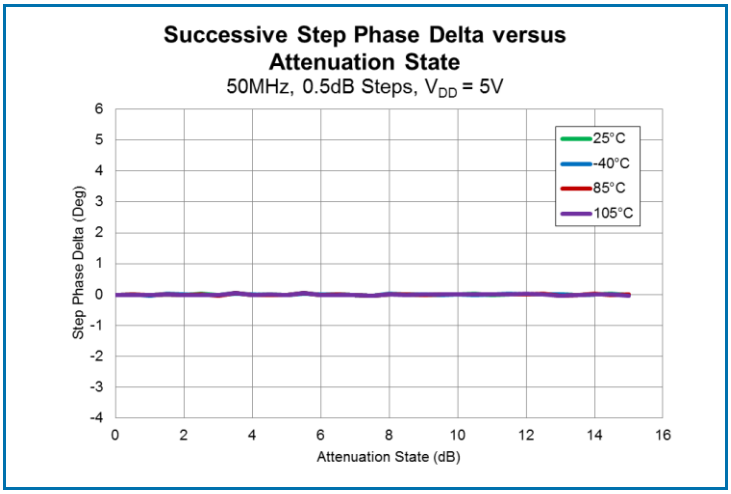
Typical Performance:

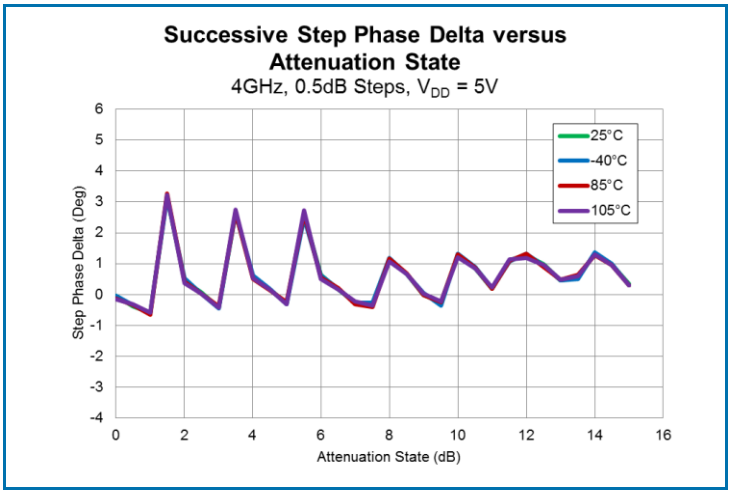








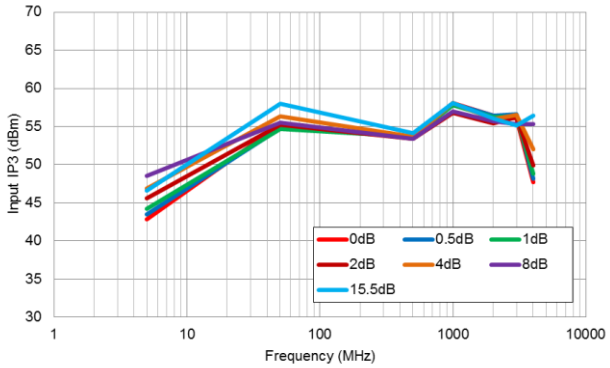




Typical Performance:

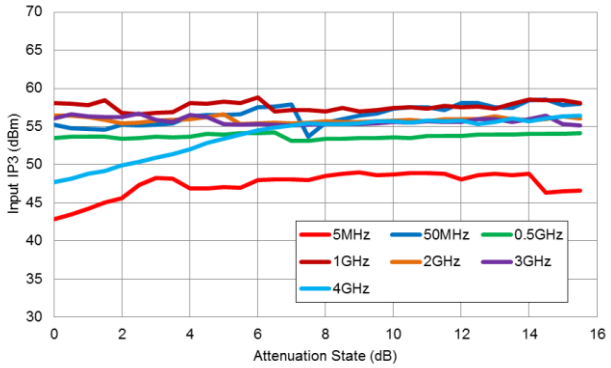
Input IP3 versus Frequency

V_{DD} = 5V, RF 50MHz to 4000MHz Pin = +18dBm/Tone,
RF 5MHz Pin = +15dBm/Tone, Temp = +25°C



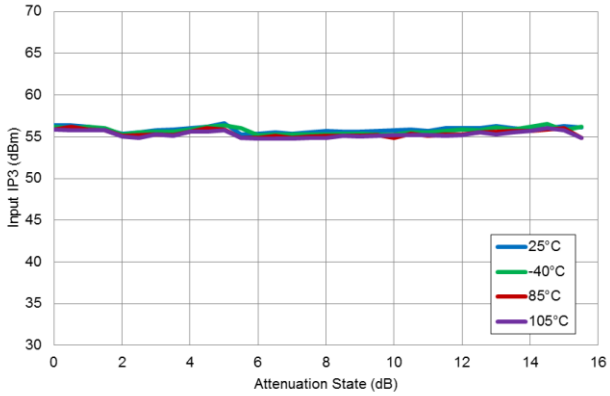
Input IP3 versus Attenuation State

V_{DD} = 5V, RF 50MHz to 4000MHz Pin = +18dBm/Tone,
RF 5MHz Pin = +15dBm/Tone, Temp = +25°C



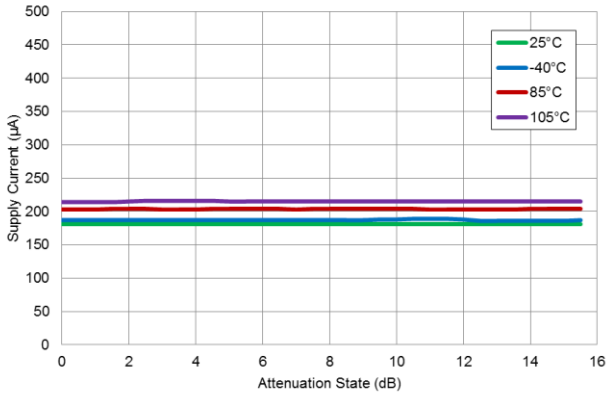
Input IP3 versus Attenuation State

RF 2GHz, V_{DD} = 5V, Pin = +18dBm/Tone

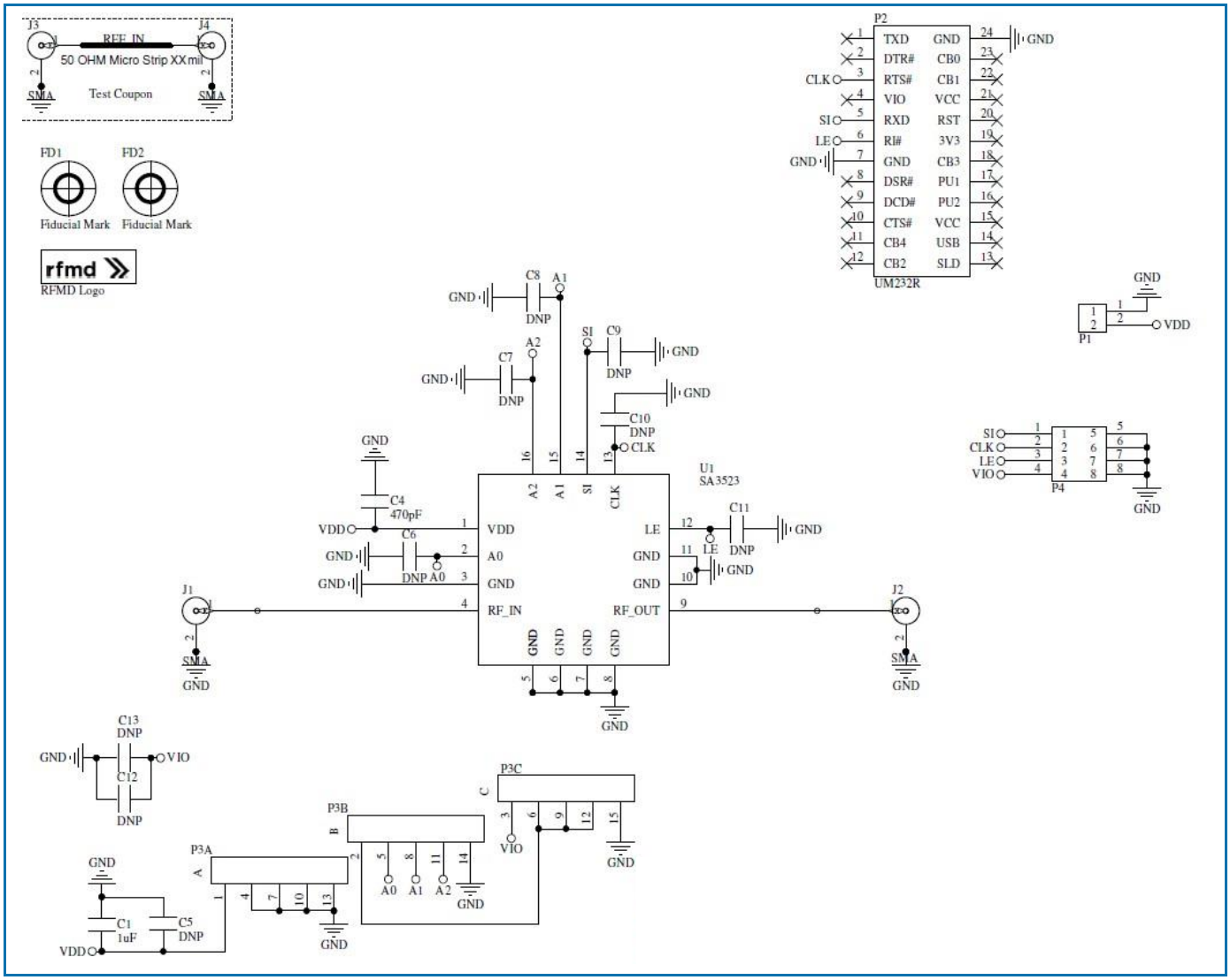


Supply Current versus Attenuation State

RF 2GHz, V_{DD} = 5V



Evaluation Board Schematic



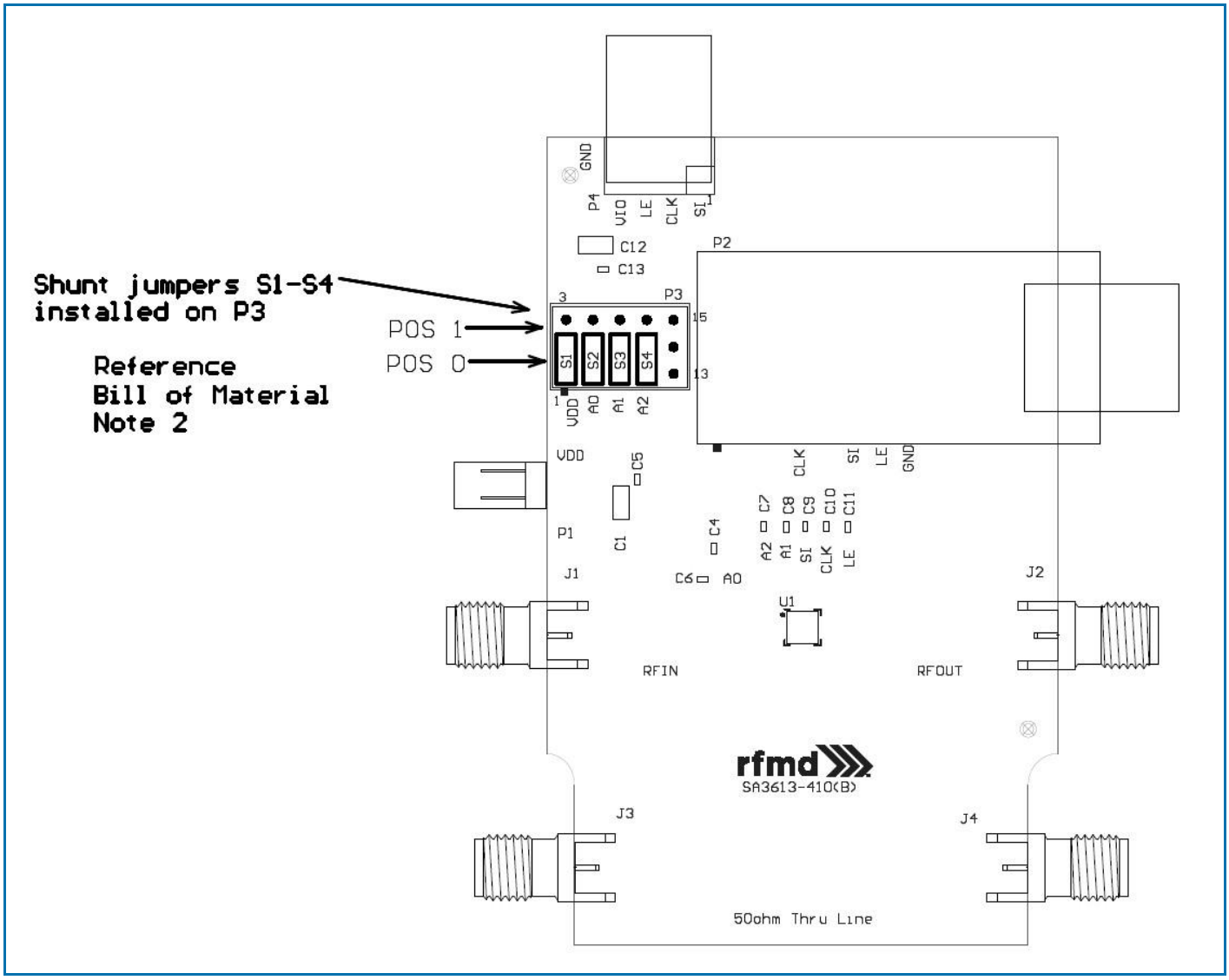
Evaluation Board Bill of Materials (BOM)

Description	Reference Designator	Manufacturer	Manufacturer's P/N
RFSA3613-410		Dynamic Details (DDI) Toronto	RFSA3613-410(B)
Digital Step Attenuator, 5MHz to 6000MHz	U1	RFMD	RFSA3523SB
CAP, 1µF, 10%, 25V, X7R, 1206	C1	Taiyo Yuden (USA), Inc.	CE TMK316BJ105KL-T
CONN, SMA, END LNCH, UNIV, HYB MNT, FLT	J1-J4	Molex	SD-73251-4000
CONN, HDR, ST, PLRZD, 2-PIN, 0.100”	P1	ITW Pancon	MPSS100-2-C
CONN, HDR, ST, 3 x 5, 0.100”, T/H	P3	Samtec Inc.	TSW-105-07-L-T
CONN, HDR, 2 x 4, RA, 0.100”, T/H	P4	Samtec Inc.	TSW-104-08-G-D-RA
CONN, SKT, 24-PIN DIP, 0.600”, T/H	P2	Aries Electronics Inc.	24-6518-10
MOD, USB TO SERIAL UART, SSOP-28	M1 (See Note 1)	Future Technology Devices Int’l	UM232R
CAP, 470pF, 5%, 50V, C0G, 0402	C4	Murata Electronics	GRM1555C1H471JA01D
Jumpers, 2-Pin	S1-S4 (See Note 2)	3M Interconnect Solutions	929950-00
DNP	C5-C13	N/A	N/A

Notes:

1. M1 should be mounted into P2 with respect to the Pin 1 alignment of M1 andP2.
2. Install S1-S4 into P3 as indicated on Evaluation Board Assembly Diagram

Evaluation Board Assembly Drawing



Evaluation Board Jumper Programming

Jumpers	Connector	Signal	Position	U1 Connection	Comment
S1	P3	Logic Voltage	**0**	VDD (From P1)	
			1	VIO (From P4)	
S2		AO	**0**	GND	External Address
			1	U1_VDD	
S3		A1	**0**	GND	External Address
			1	U1_VDD	
S4		A2	**0**	GND	External Address
			1	U1_VDD	

Note: Default jumper settings are **BOLD**.

Evaluation Board Programming Using USB Interface

Serial Addressable Mode

All programming jumpers on the evaluation board are set to the default values indicated in the table. Refer to the Control Bit Generator (CBG) Software Reference Manual for detailed instructions on how to setup the software for use. Apply the supply voltage to P1. Select 'RFSA3523' from the RFMD Parts List of the CBG user interface. Set the attenuation value using the CBG user interface. The attenuator is set to the desired state and measurements can be taken. Note that the external address bits must all be set to '0' when using the USB interface as the CBG software does not have the capability to set the external address in the serial data stream at this time.

Evaluation Board Programming Using External Bus

Serial Addressable Mode

This configuration allows the user to control the attenuator through the P4 connector using an external harness. Remove the USB interface board if it is currently installed on the evaluation board. Connect a user-supplied harness to the P4 connector. Note that the top row of P4 contains the serial bus signals and the bottom row is ground. Programming jumper S1 is set to '0'. External address jumpers S2 through S4 can be set to any value desired by the user. Apply the supply voltage to P1. Send the appropriate signals onto the serial bus lines in accordance with the Serial Addressable Mode Timing Diagram. The attenuator is set to the desired state and measurements can be taken.

Default Power-up State

This default attenuation state is maximum (15.5dB) when supply voltage is applied to the attenuator. The LE signal must be held to logic '0' during power-up.

Pin Names and Descriptions

Pin	Name	Description
1	VDD	Supply Voltage
2	A0	A0 External Address Pin
3	GND	Ground Pin
4	RFIN	RF Input Pin Incident RF power must enter this pin for rated thermal performance and reliability Do not apply DC power to this pin. Pin may be DC grounded externally and is grounded thru resistors internal to the part.
5	GND	Ground Pin
6	GND	Ground Pin
7	GND	Ground Pin
8	GND	Ground Pin
9	RFOUT	RF Output Pin; Do not apply DC power to this pin. Pin may be DC grounded externally and is grounded thru resistors internal to the part.
10	GND	Ground Pin
11	GND	Ground Pin
12	LE	Latch Enable The leading edge of signal on LE causes the attenuator to change state
13	CLK	Serial Clock Input
14	SI	Serial data Input
15	A1	A1 External Address Pin
16	A2	A2 External Address Pin

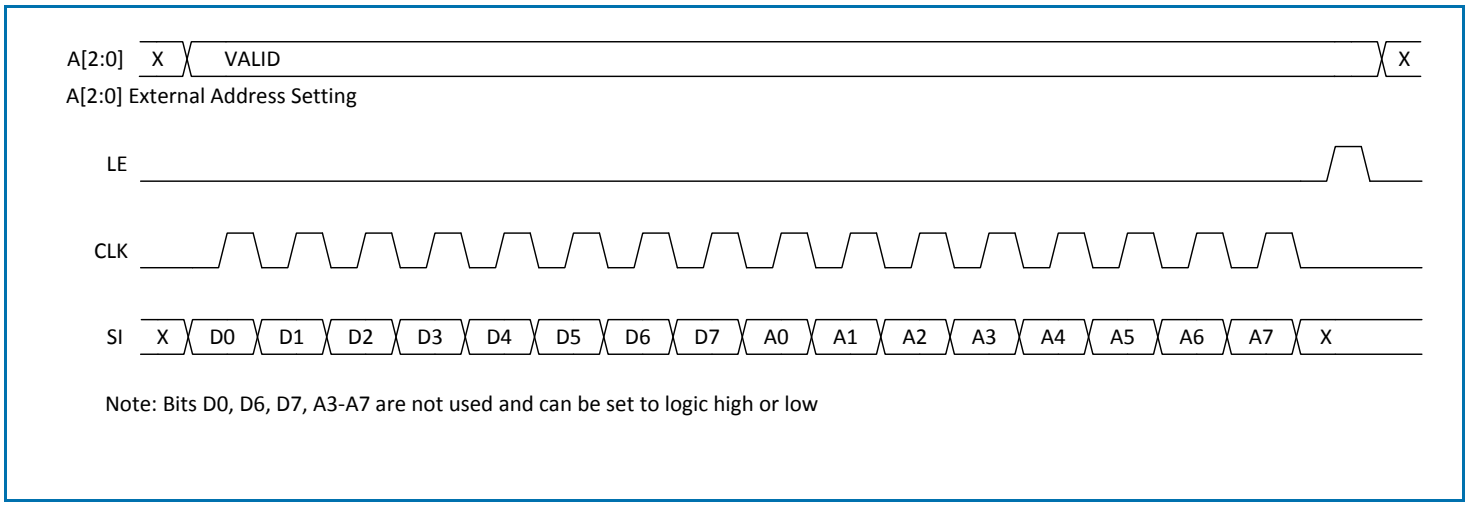
Serial Addressable Mode Attenuation Word Truth Table

Attenuation Word								Attenuation State
D7	D6	D5	D4	D3	D2	D1 (LSB)	D0	
X	X	L	L	L	L	L	X	0dB / Reference Insertion Loss
X	X	L	L	L	L	H	X	0.5dB
X	X	L	L	L	H	L	X	1dB
X	X	L	L	H	L	L	X	2dB
X	X	L	H	L	L	L	X	4dB
X	X	H	L	L	L	L	X	8dB
X	X	H	H	H	H	H	X	15.5dB

Serial Addressable Mode Address Word Truth Table

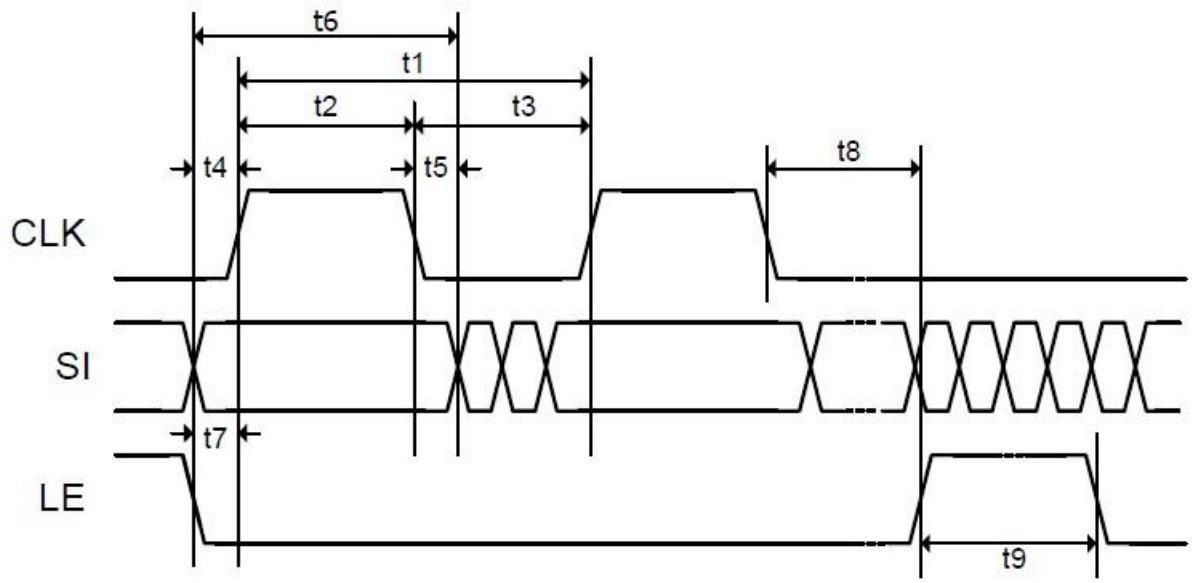
Address Word								Address Setting
A7	A6	A5	A4	A3	A2 (MSB)	A1	A0	
X	X	X	X	X	L	L	L	000
X	X	X	X	X	L	L	H	001
X	X	X	X	X	L	H	L	010
X	X	X	X	X	L	H	H	011
X	X	X	X	X	H	L	L	100
X	X	X	X	X	H	L	H	101
X	X	X	X	X	H	H	L	110
X	X	X	X	X	H	H	H	111

Serial Addressable Mode Timing Diagram



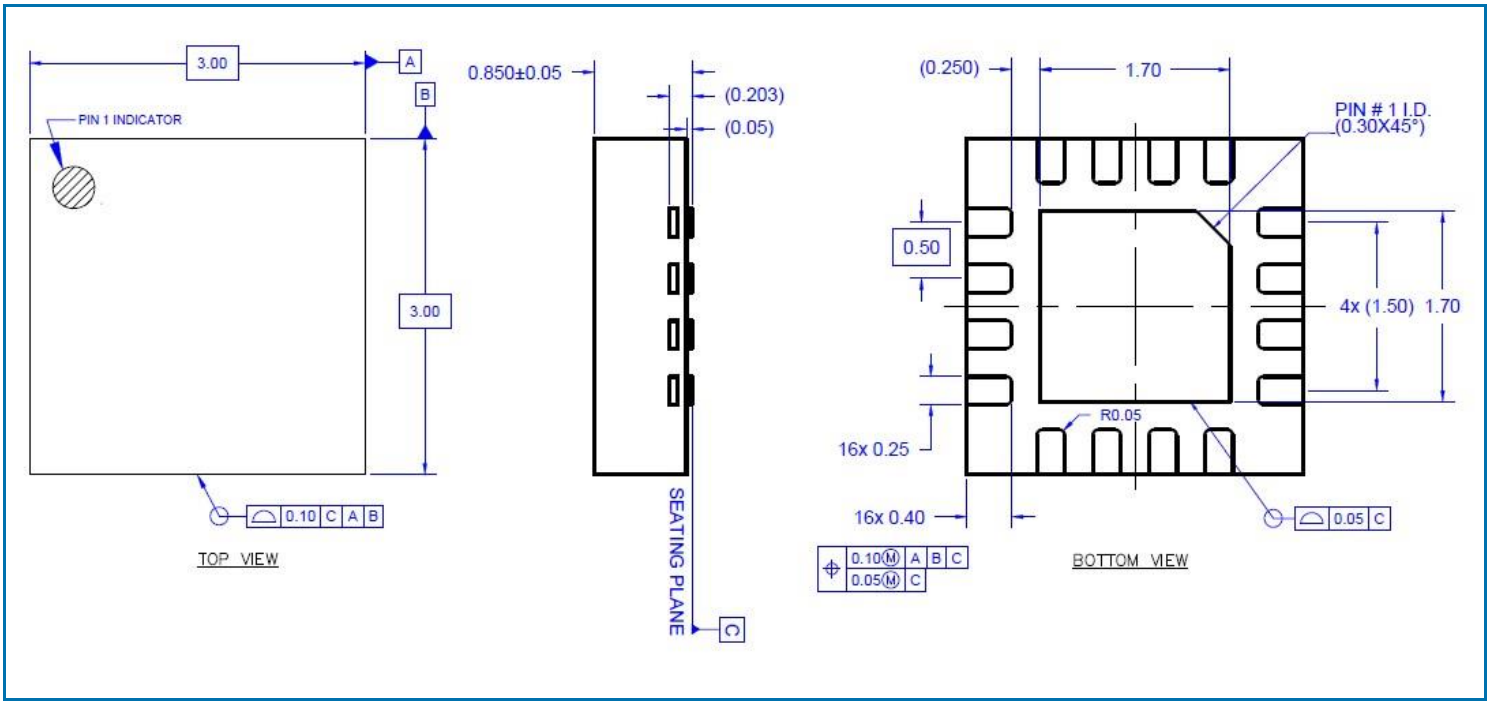
Note: Bits D0, D6, D7, A3-A7 are not used and can be set to logic high or low

Serial Bus Timing Specifications

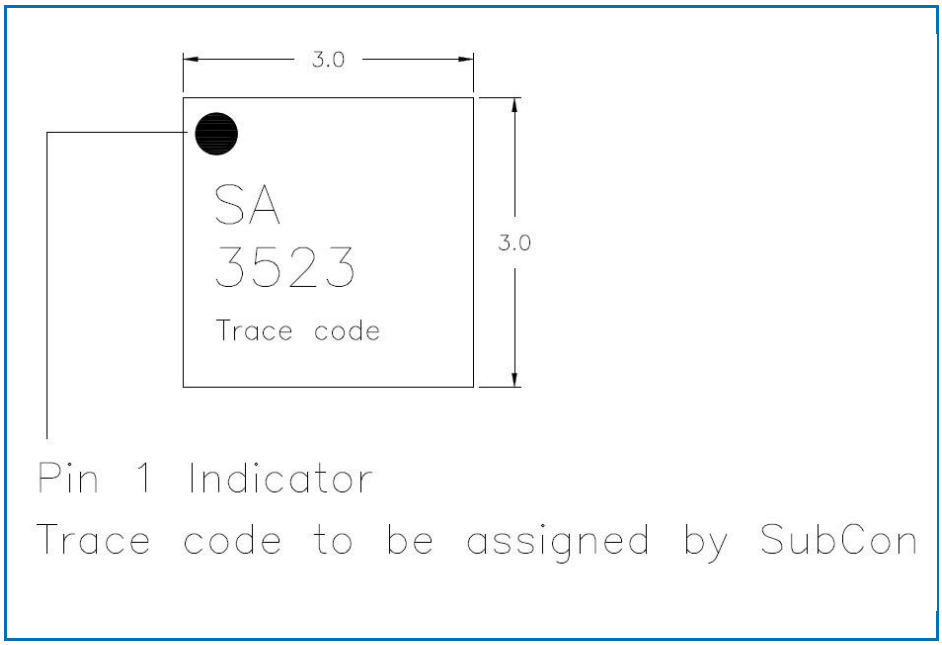


Parameter	Limit	Unit	Comment
t1	25	MHz max	CLK Frequency
t2	20	ns min	CLK High
t3	20	ns min	CLK Low
t4	5	ns min	SI to CLK Setup Time
t5	5	ns min	SI to CLK Hold Time
t6	30	ns min	SI Valid
t7	5	ns min	LE to CLK Setup Time
t8	5	ns min	CLK to LE Setup Time
t9	10	ns min	LE Pulse Width

Package Drawing (Dimensions in millimeters)



Branding Diagram



Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9